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High temperature half-metallicity in 2D CoGa_2X_4 ($\text{X}=\text{S}, \text{Se}, \text{Te}$)

The recent discovery of intrinsic ferromagnetic CrI_3 and $\text{Gr}_2\text{Ge}_2\text{Te}_6$ within 70 K creates huge potential for spintronic applications of 2D van der Waals crystals.^[1, 2] However, large spin polarization, high phase transition temperature and controllable spin direction are crucial requirements for the spintronic applications of atomically thin magnets. Here, we discover a class of CoGa_2X_4 ($\text{X}=\text{S}, \text{Se}$ or Te) monolayer with triangular lattice exhibiting intrinsic half-metallic ferromagnetism. They have large spin gaps in the semiconducting channel, ranging from 2.7 eV for CoGa_2S_4 to 1.7 eV for CoGa_2Te_4 , which makes them stable against the spin flip under weak external disturbances. The magnetocrystalline anisotropy (MAE) calculation with spin-orbital coupling SOC indicates CoGa_2X_4 possesses easy plane magnetization, which is expected to have a Berezinskii–Kosterlitz–Thouless transition by classical XY model. The critical temperatures are 886 K, 752 K, and 719 K for CoGa_2S_4 , CoGa_2Se_4 and CoGa_2Te_4 , respectively. The MAE of CoGa_2X_4 are 47 μeV for $\text{X}=\text{S}$, 84 μeV for $\text{X}=\text{Se}$ and 622 μeV for $\text{X}=\text{Te}$. The in-plane magnetic moments change to out-of-plane direction if the lattice constants increase from 3.623 Å to 3.75 Å (increase 3.5%), which can be realized through substrate mismatch or other bilayer strain methods. The proposed half-metallic CoGa_2X_4 system belongs to the big family of layered AB_2X_4 compounds, which is a significant part of layer-type phases. The stable and steerable magnetization with 100% spin-polarization ratio of CoGa_2X_4 would broaden the available design space for spintronics, and connect the magnetic with electronic properties together in 2D materials.

References

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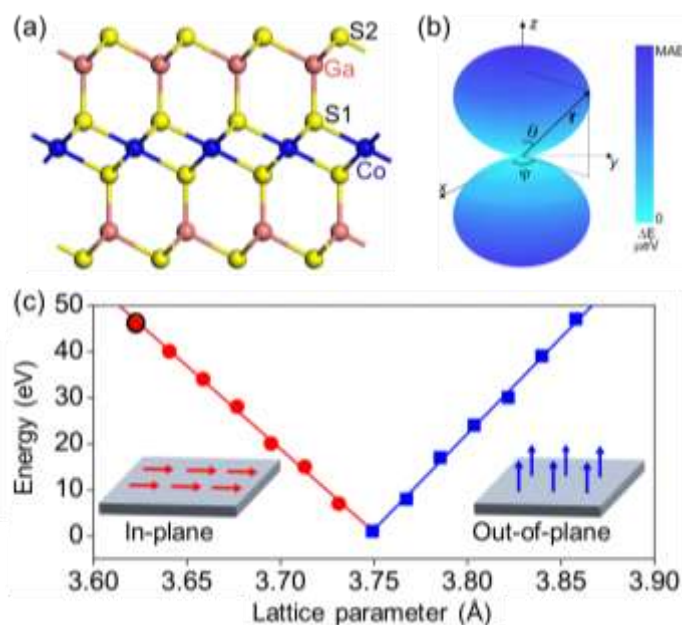


Figure 1: (a) Side view of CoGa_2X_4 structure; (b) Schematic map of MAE for CoGa_2X_4 monolayer. (c) With the increase of lattice parameters, the in-plane magnetic moments vary to out-of-plane direction.